

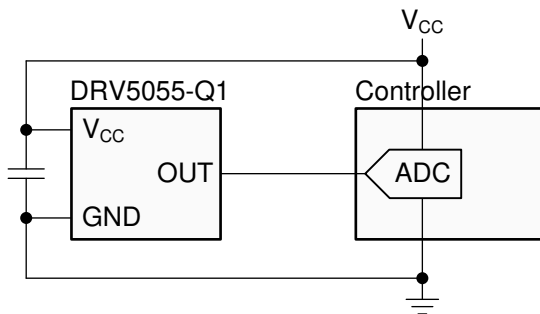
# DRV5055 レシオメトリック・リニア・ホール効果センサ

## 1 特長

- レシオメトリック・リニア・ホール効果磁気センサ
- 3.3V および 5V の電源で動作
- $V_{CC}/2$  の静止オフセット付きのアナログ出力
- 磁気感度オプション ( $V_{CC} = 5V$  時)
  - A1/Z1: 100mV/mT、 $\pm 21mT$  範囲
  - A2/Z2: 50mV/mT、 $\pm 42mT$  範囲
  - A3/Z3: 25mV/mT、 $\pm 85mT$  範囲
  - A4/Z4: 12.5mV/mT、 $\pm 169mT$  範囲
- 高速な 20kHz センシング帯域幅
- $\pm 1mA$  駆動の低ノイズ出力
- A バージョンでは磁石の温度ドリフトの補償があるが、Z バージョンでは補償なし
- 標準の産業用パッケージ:
  - 表面実装の SOT-23
  - スルーホールの TO-92

## 2 アプリケーション

- 高精度の位置センシング
- 産業用オートメーションおよびロボティクス
- 家電製品
- ゲームパッド、ペダル、キーボード、トリガ
- 高さレベリング、傾き、重量の測定
- 流量率測定
- 医療機器
- 絶対角度のエンコード
- 電流検出



代表的な回路図

## 3 概要

DRV5055 は、リニア・ホール効果センサで、磁束密度に正比例して応答します。このデバイスは、広範なアプリケーションにおいて、正確な位置センシングに使用できます。

このデバイスは、3.3V または 5V の電源で動作します。磁界が存在しないとき、アナログ出力は  $V_{CC}$  の半分に駆動されます。出力は、印加される磁束密度に対して線形的に変化し、4 つの感度オプションによって、必要なセンシング範囲に基づいて出力電圧スイングを最大化できます。磁界の N 極と S 極がそれぞれ固有の電圧を生成します。

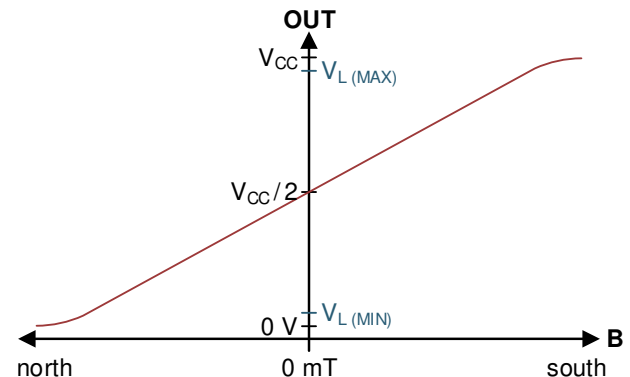
パッケージの上面に垂直な磁束が検出され、2 つのパッケージ・オプションでセンシング方向が異なります。

このデバイスは、レシオメトリック・アーキテクチャを使用し、外部のアナログ / デジタル・コンバータ (ADC) が基準として同じ  $V_{CC}$  を使用しているとき、 $V_{CC}$  許容範囲から誤差を除去できます。さらに、デバイスには磁石温度補償が搭載されており、磁石のドリフトを補償することで、 $-40^{\circ}C \sim +125^{\circ}C$  の広い温度範囲にわたって線形のパフォーマンスを実現します。磁石のドリフトの温度補償を行わないデバイスも選択できます。

### パッケージ情報

| 部品番号    | パッケージ (1)       | パッケージ・サイズ (2)   |
|---------|-----------------|-----------------|
| DRV5055 | DBZ (SOT-23, 3) | 2.92mm × 2.37mm |
|         | LPG (TO-92, 3)  | 4.00mm × 1.52mm |

- 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。
- パッケージサイズ (長さ×幅) は公称値であり、該当する場合はピンも含まれます



磁気応答 (A1、A2、A3、A4 バージョン)



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## 4 Pin Configuration and Functions

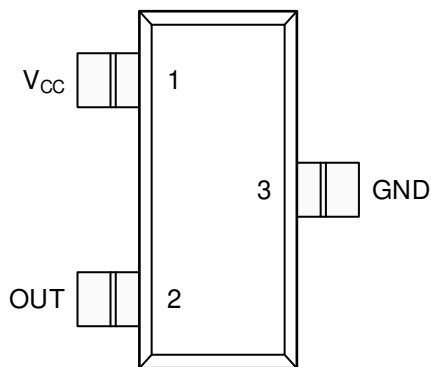


図 4-1. DBZ Package 3-Pin SOT-23 Top View

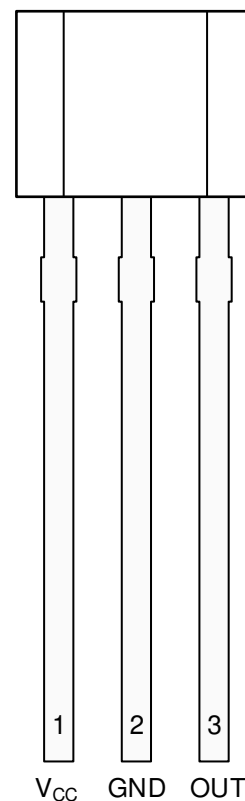


図 4-2. LPG Package 3-Pin TO-92 Top View

表 4-1. Pin Functions

| PIN             |        |       | I/O | DESCRIPTION                                                                                                             |
|-----------------|--------|-------|-----|-------------------------------------------------------------------------------------------------------------------------|
| NAME            | SOT-23 | TO-92 |     |                                                                                                                         |
| V <sub>CC</sub> | 1      | 1     | —   | Power supply. TI recommends connecting this pin to a ceramic capacitor to ground with a value of at least 0.01 $\mu$ F. |

**表 4-1. Pin Functions (続き)**

| PIN  |        |       | I/O | DESCRIPTION      |
|------|--------|-------|-----|------------------|
| NAME | SOT-23 | TO-92 |     |                  |
| OUT  | 2      | 3     | O   | Analog output    |
| GND  | 3      | 2     | —   | Ground reference |

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                                                |                 | MIN       | MAX                   | UNIT |
|------------------------------------------------|-----------------|-----------|-----------------------|------|
| Power supply voltage                           | V <sub>CC</sub> | –0.3      | 7                     | V    |
| Output voltage                                 | OUT             | –0.3      | V <sub>CC</sub> + 0.3 | V    |
| Magnetic flux density, B <sub>MAX</sub>        |                 | Unlimited |                       | T    |
| Operating junction temperature, T <sub>J</sub> |                 | –40       | 170                   | °C   |
| Storage temperature, T <sub>stg</sub>          |                 | –65       | 150                   | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 5.2 ESD Ratings

|                    |                         |                                                                                | VALUE | UNIT |
|--------------------|-------------------------|--------------------------------------------------------------------------------|-------|------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2500 | V    |
|                    |                         | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±750  |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.  
 (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                 |                                              | MIN | MAX  | UNIT |
|-----------------|----------------------------------------------|-----|------|------|
| V <sub>CC</sub> | Power supply voltage <sup>(1)</sup>          | 3   | 3.63 | V    |
|                 |                                              | 4.5 | 5.5  |      |
| I <sub>O</sub>  | Output continuous current                    | –1  | 1    | mA   |
| T <sub>A</sub>  | Operating ambient temperature <sup>(2)</sup> | –40 | 125  | °C   |

- (1) There are two isolated operating V<sub>CC</sub> ranges.  
 (2) Power dissipation and thermal limits must be observed.

### 5.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | DRV5055      |             | UNIT |
|-------------------------------|----------------------------------------------|--------------|-------------|------|
|                               |                                              | SOT-23 (DBZ) | TO-92 (LPG) |      |
|                               |                                              | 3 PINS       | 3 PINS      |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 170          | 121         | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 66           | 67          | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 49           | 97          | °C/W |
| Y <sub>JT</sub>               | Junction-to-top characterization parameter   | 1.7          | 7.6         | °C/W |
| Y <sub>JB</sub>               | Junction-to-board characterization parameter | 48           | 97          | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 5.5 Electrical Characteristics

for  $V_{CC} = 3\text{ V}$  to  $3.63\text{ V}$  and  $4.5\text{ V}$  to  $5.5\text{ V}$ , over operating free-air temperature range (unless otherwise noted)

| PARAMETER |                                      | TEST CONDITIONS <sup>(1)</sup>                               | MIN                     | TYP  | MAX | UNIT                         |
|-----------|--------------------------------------|--------------------------------------------------------------|-------------------------|------|-----|------------------------------|
| $I_{CC}$  | Operating supply current             | $V_{CC} = 5.0\text{ V}$ , $B = 0\text{ mT}$                  |                         | 3    | 5   | mA                           |
| $I_{CC}$  | Operating supply current             | $V_{CC} = 3.3\text{ V}$ , $B = 0\text{ mT}$                  |                         | 2    | 4   | mA                           |
| $t_{ON}$  | Power-on time                        | $V_{CC} = 5.0\text{ V}$ , $B = 0\text{ mT}$ , no load on OUT |                         | 40   | 100 | $\mu\text{s}$                |
| $t_{ON}$  | Power-on time                        | $V_{CC} = 3.3\text{ V}$ , $B = 0\text{ mT}$ , no load on OUT |                         | 40   | 70  | $\mu\text{s}$                |
| $f_{BW}$  | Sensing bandwidth                    |                                                              |                         | 20   |     | kHz                          |
| $t_d$     | Propagation delay time               | From change in $B$ to change in OUT                          |                         | 10   | 15  | $\mu\text{s}$                |
| $B_{ND}$  | Input-referred RMS noise density     | $V_{CC} = 5\text{ V}$                                        |                         | 130  |     | $\text{nT}/\sqrt{\text{Hz}}$ |
|           |                                      | $V_{CC} = 3.3\text{ V}$                                      |                         | 215  |     |                              |
| $B_N$     | Input-referred noise                 | $B_{ND} \times 6.6 \times \sqrt{20\text{ kHz}}$              | $V_{CC} = 5\text{ V}$   | 0.12 |     | $\text{mT}_{PP}$             |
|           |                                      |                                                              | $V_{CC} = 3.3\text{ V}$ | 0.2  |     |                              |
| $V_N$     | Output-referred noise <sup>(2)</sup> | $B_N \times S$                                               | DRV5055A1/<br>DRV5055Z1 | 12   |     | $\text{mV}_{PP}$             |
|           |                                      |                                                              | DRV5055A2/<br>DRV5055Z2 | 6    |     |                              |
|           |                                      |                                                              | DRV5055A3/<br>DRV5055Z3 | 3    |     |                              |
|           |                                      |                                                              | DRV5055A4/<br>DRV5055Z4 | 1.5  |     |                              |

(1)  $B$  is the applied magnetic flux density.

(2)  $V_N$  describes voltage noise on the device output. If the full device bandwidth is not needed, noise can be reduced with an RC filter.

## 5.6 Magnetic Characteristics

for  $V_{CC} = 3\text{ V}$  to  $3.63\text{ V}$  and  $4.5\text{ V}$  to  $5.5\text{ V}$ , over operating free-air temperature range (unless otherwise noted)

| PARAMETER        |                                                                 | TEST CONDITIONS <sup>(1)</sup>                              |                         | MIN                   | TYP                   | MAX  | UNIT  |
|------------------|-----------------------------------------------------------------|-------------------------------------------------------------|-------------------------|-----------------------|-----------------------|------|-------|
| V <sub>Q</sub>   | Quiescent voltage                                               | B = 0 mT, T <sub>A</sub> = 25°C                             | V <sub>CC</sub> = 5 V   | 2.43                  | 2.5                   | 2.57 | V     |
|                  |                                                                 |                                                             | V <sub>CC</sub> = 3.3 V | 1.59                  | 1.65                  | 1.71 |       |
| V <sub>QAT</sub> | Quiescent voltage temperature drift                             | B = 0 mT,<br>T <sub>A</sub> = -40°C to 125°C<br>versus 25°C | V <sub>CC</sub> = 5.0 V | ±1% × V <sub>CC</sub> |                       |      | V     |
| V <sub>QAT</sub> |                                                                 |                                                             | V <sub>CC</sub> = 3.3 V | ±1% × V <sub>CC</sub> |                       |      | V     |
| V <sub>QRE</sub> | Quiescent voltage ratiometry error                              |                                                             |                         | ±0.2                  |                       |      | %     |
| V <sub>QAL</sub> | Quiescent voltage lifetime drift                                | High-temperature operating stress for 1000 hours            |                         | <0.5                  |                       |      | 1 %   |
| S                | Sensitivity                                                     | V <sub>CC</sub> = 5 V,<br>T <sub>A</sub> = 25°C             | DRV5055A1/<br>DRV5055Z1 | 95                    | 100                   | 105  | mV/mT |
|                  |                                                                 |                                                             | DRV5055A2/<br>DRV5055Z2 | 47.5                  | 50                    | 52.5 |       |
|                  |                                                                 |                                                             | DRV5055A3/<br>DRV5055Z3 | 23.8                  | 25                    | 26.2 |       |
|                  |                                                                 |                                                             | DRV5055A4/<br>DRV5055Z4 | 11.9                  | 12.5                  | 13.2 |       |
|                  |                                                                 | V <sub>CC</sub> = 3.3 V,<br>T <sub>A</sub> = 25°C           | DRV5055A1/<br>DRV5055Z1 | 57                    | 60                    | 63   |       |
|                  |                                                                 |                                                             | DRV5055A2/<br>DRV5055Z2 | 28.5                  | 30                    | 31.5 |       |
|                  |                                                                 |                                                             | DRV5055A3/<br>DRV5055Z3 | 14.3                  | 15                    | 15.8 |       |
|                  |                                                                 |                                                             | DRV5055A4/<br>DRV5055Z4 | 7.1                   | 7.5                   | 7.9  |       |
| B <sub>L</sub>   | Linear magnetic sensing range <sup>(2)</sup>                    | V <sub>CC</sub> = 5 V,<br>T <sub>A</sub> = 25°C             | DRV5055A1/<br>DRV5055Z1 | ±21                   |                       |      | mT    |
|                  |                                                                 |                                                             | DRV5055A2/<br>DRV5055Z2 | ±42                   |                       |      |       |
|                  |                                                                 |                                                             | DRV5055A3/<br>DRV5055Z3 | ±85                   |                       |      |       |
|                  |                                                                 |                                                             | DRV5055A4/<br>DRV5055Z4 | ±169                  |                       |      |       |
|                  |                                                                 | V <sub>CC</sub> = 3.3 V,<br>T <sub>A</sub> = 25°C           | DRV5055A1/<br>DRV5055Z1 | ±22                   |                       |      |       |
|                  |                                                                 |                                                             | DRV5055A2/<br>DRV5055Z2 | ±44                   |                       |      |       |
|                  |                                                                 |                                                             | DRV5055A3/<br>DRV5055Z3 | ±88                   |                       |      |       |
|                  |                                                                 |                                                             | DRV5055A4/<br>DRV5055Z4 | ±176                  |                       |      |       |
| V <sub>L</sub>   | Linear range of output voltage                                  |                                                             |                         | 0.2                   | V <sub>CC</sub> – 0.2 |      | V     |
| S <sub>TC</sub>  | Sensitivity temperature compensation for magnets <sup>(3)</sup> | DRV5055A1/A2/A3/A4                                          |                         | 0.04                  | 0.12                  | 0.2  | %/°C  |
| S <sub>TC</sub>  | Sensitivity temperature compensation for magnets <sup>(3)</sup> | DRV5055Z1/Z2/Z3/Z4                                          |                         | 0                     |                       |      | %/°C  |
| S <sub>LE</sub>  | Sensitivity linearity error                                     | V <sub>OUT</sub> is within V <sub>L</sub>                   |                         | ±1                    |                       |      | %     |
| S <sub>SE</sub>  | Sensitivity symmetry error                                      | V <sub>OUT</sub> is within V <sub>L</sub>                   |                         | ±1                    |                       |      | %     |

for  $V_{CC} = 3\text{ V}$  to  $3.63\text{ V}$  and  $4.5\text{ V}$  to  $5.5\text{ V}$ , over operating free-air temperature range (unless otherwise noted)

| PARAMETER      |                              | TEST CONDITIONS <sup>(1)</sup>                                                        | MIN  | TYP  | MAX | UNIT |
|----------------|------------------------------|---------------------------------------------------------------------------------------|------|------|-----|------|
| $S_{RE}$       | Sensitivity ratiometry error | $T_A = 25^\circ\text{C}$ ,<br>with respect to $V_{CC} = 3.3\text{ V}$ or $5\text{ V}$ | -2.5 |      | 2.5 | %    |
| $S_{\Delta L}$ | Sensitivity lifetime drift   | High-temperature operating stress for<br>1000 hours                                   |      | <0.5 | 1   | %    |

(1)  $B$  is the applied magnetic flux density.

(2)  $B_L$  describes the minimum linear sensing range at  $25^\circ\text{C}$  taking into account the maximum  $V_Q$  and Sensitivity tolerances.

(3)  $S_{TC}$  describes the rate the device increases Sensitivity with temperature.

## 5.7 Typical Characteristics

for  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

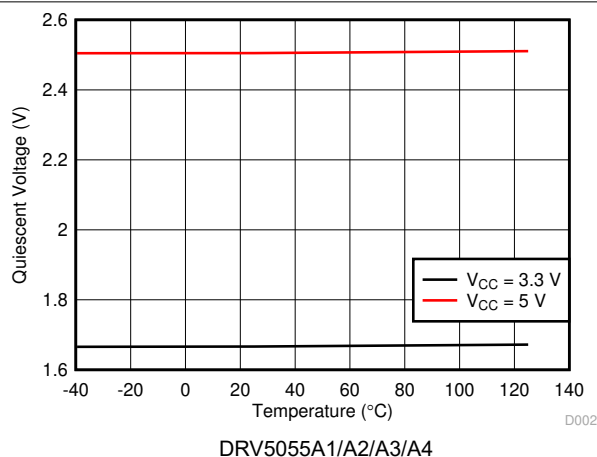


Figure 5-1. Quiescent Voltage vs Temperature

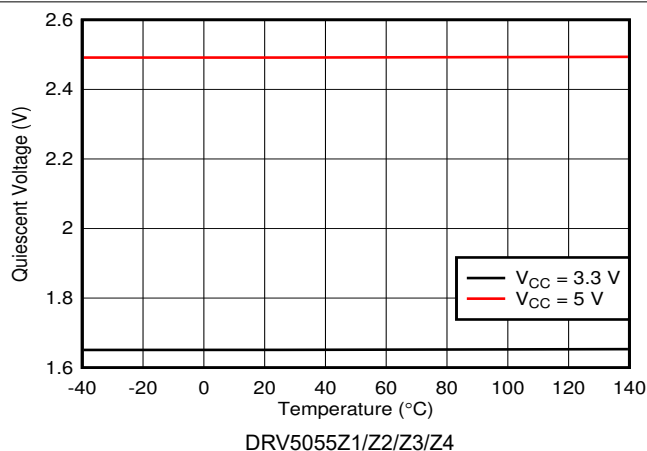


Figure 5-2. Quiescent Voltage vs Temperature

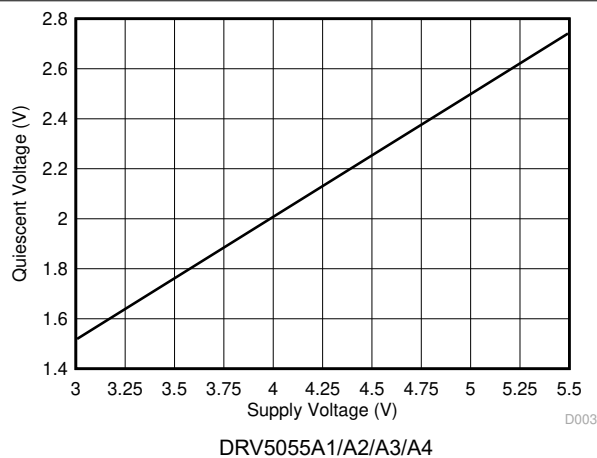


Figure 5-3. Quiescent Voltage vs Supply Voltage

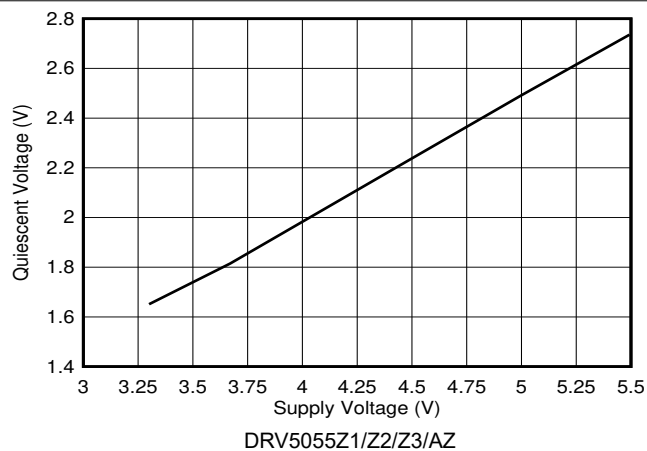


Figure 5-4. Quiescent Voltage vs Supply Voltage

## 5.7 Typical Characteristics (continued)

for  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

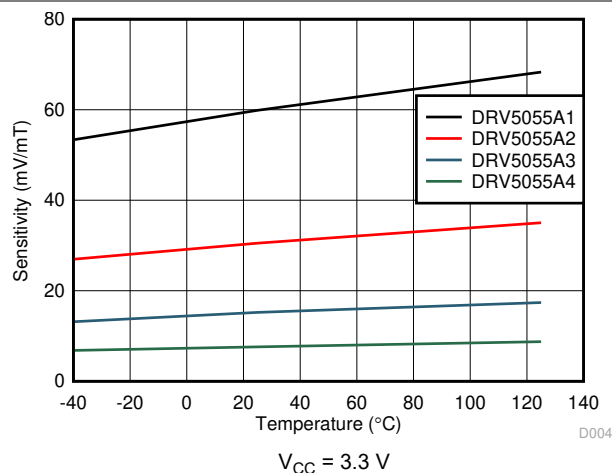


图 5-5. Sensitivity vs Temperature

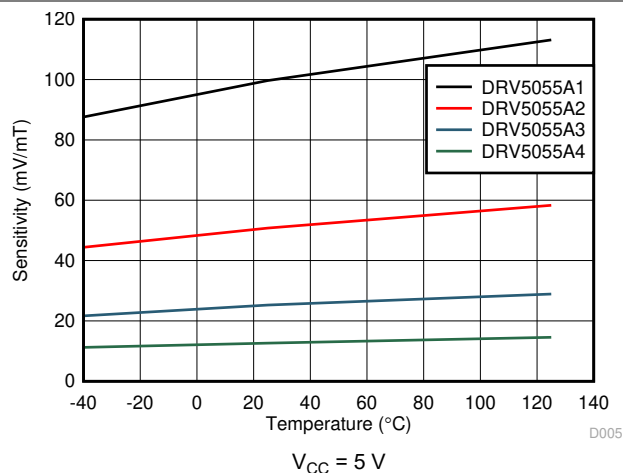


图 5-6. Sensitivity vs Temperature

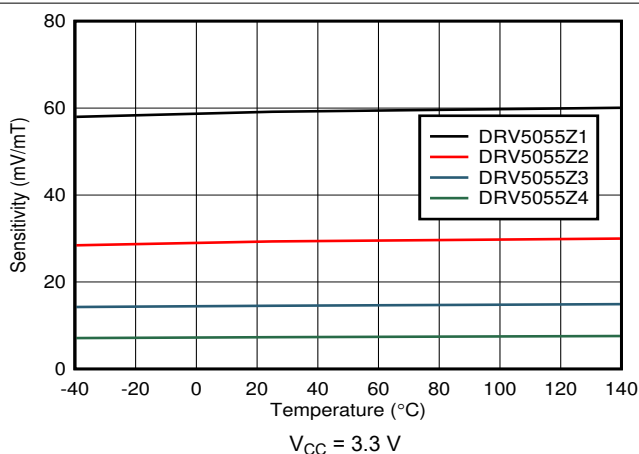


图 5-7. Sensitivity vs Temperature

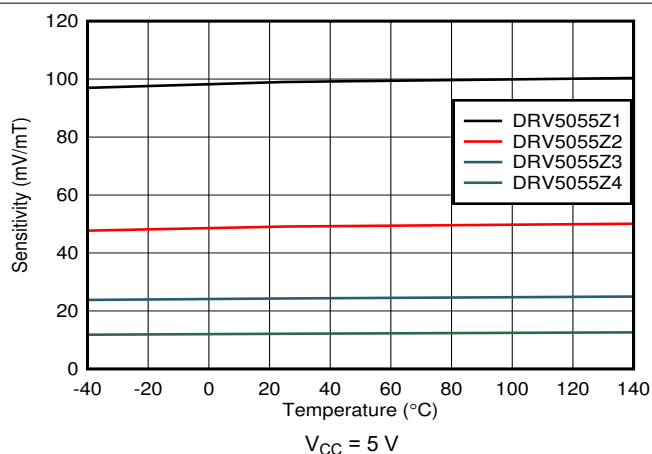


图 5-8. Sensitivity vs Temperature

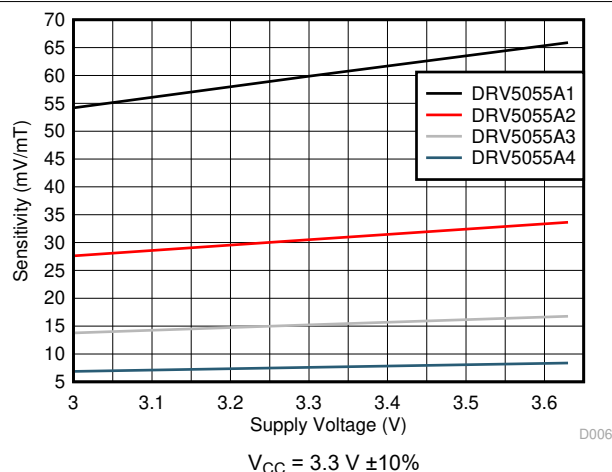


图 5-9. Sensitivity vs Supply Voltage

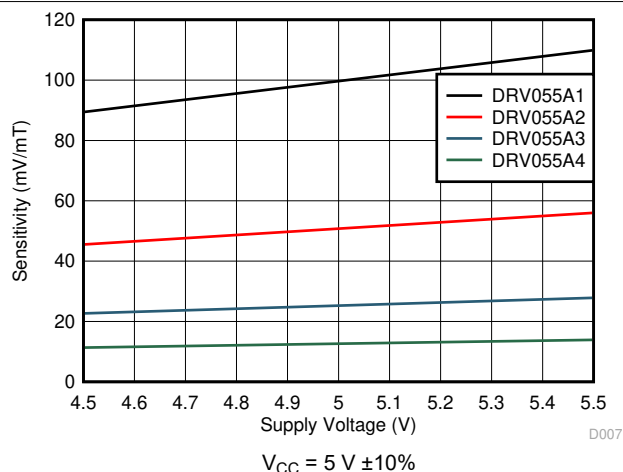
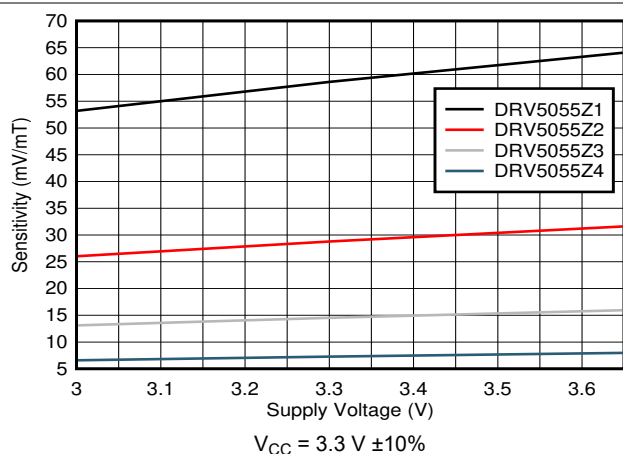


图 5-10. Sensitivity vs Supply Voltage

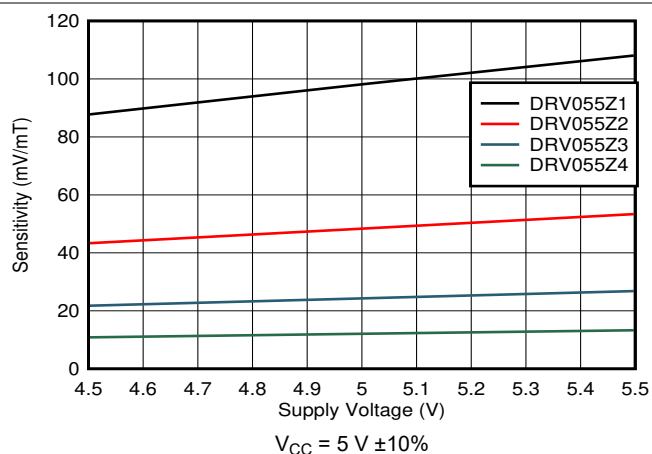


## 5.7 Typical Characteristics (continued)

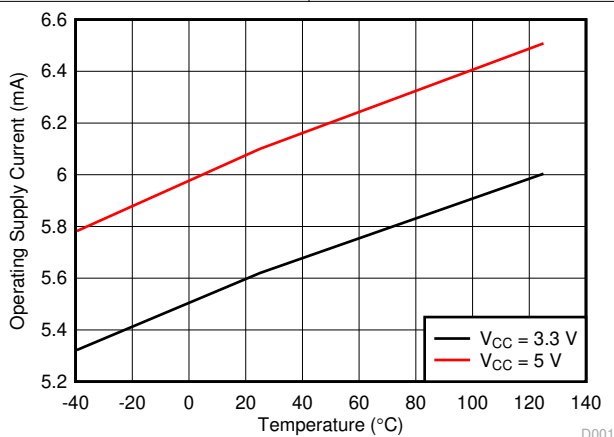
for  $T_A = 25^\circ\text{C}$  (unless otherwise noted)



5-11. Sensitivity vs Supply Voltage



5-12. Sensitivity vs Supply Voltage



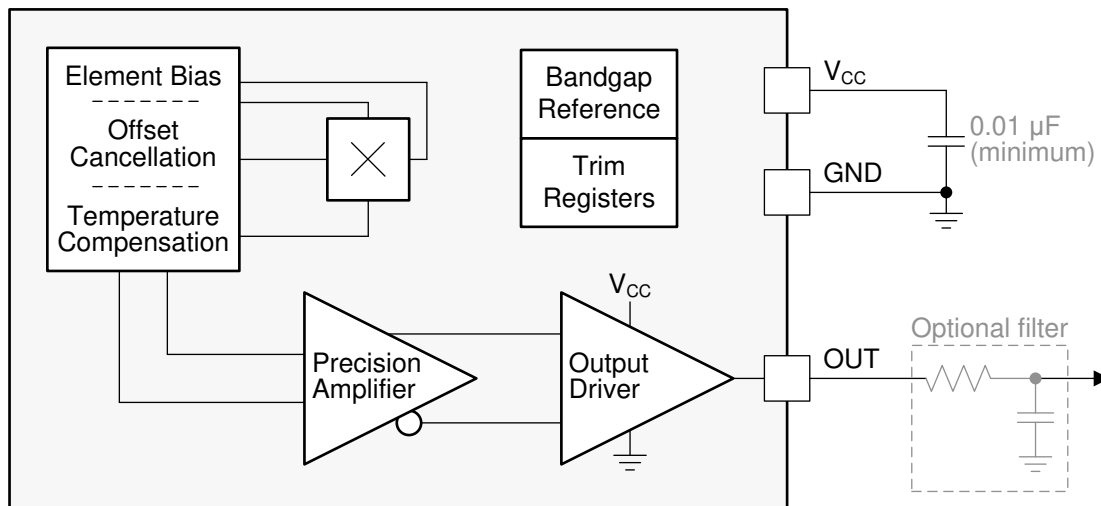
5-13. Operating Supply Current vs Temperature

## 6 Detailed Description

### 6.1 Overview

The DRV5055 is a 3-pin linear Hall effect sensor with fully integrated signal conditioning, temperature compensation circuits, mechanical stress cancellation, and amplifiers. The device operates from 3.3-V and 5-V ( $\pm 10\%$ ) power supplies, measures magnetic flux density, and outputs a proportional analog voltage that is referenced to  $V_{CC}$ .

### 6.2 Functional Block Diagram



### 6.3 Feature Description

#### 6.3.1 Magnetic Flux Direction

As shown in 図 6-1, the DRV5055 is sensitive to the magnetic field component that is perpendicular to the top of the package.

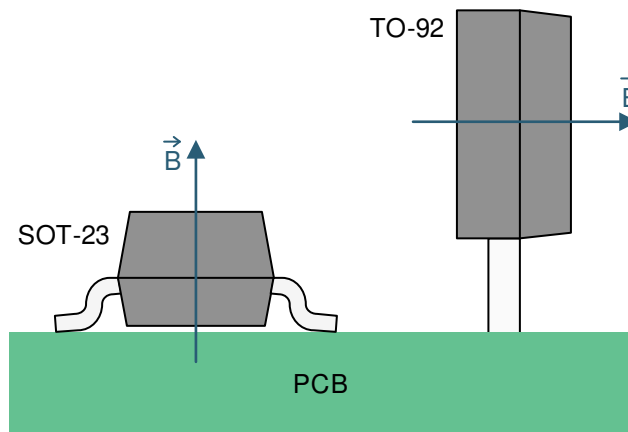


図 6-1. Direction of Sensitivity

Magnetic flux that travels from the bottom to the top of the package is considered positive in this document. This condition exists when a south magnetic pole is near the top (marked-side) of the package. Magnetic flux that travels from the top to the bottom of the package results in negative millitesla values.

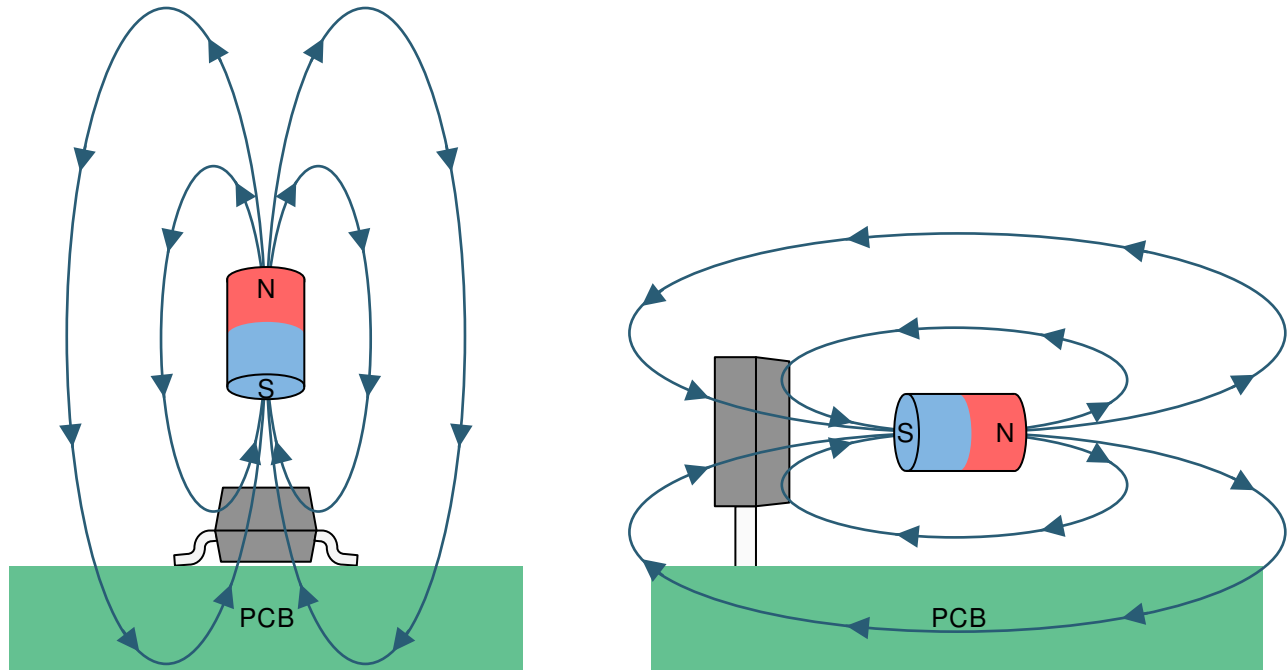


図 6-2. The Flux Direction for Positive B

### 6.3.2 Magnetic Response

When the DRV5055 is powered, the DRV5055 outputs an analog voltage according to 式 1:

$$V_{OUT} = V_Q + B \times (\text{Sensitivity}_{(25^\circ\text{C})} \times (1 + S_{TC} \times (T_A - 25^\circ\text{C}))) \quad (1)$$

where

- $V_Q$  is typically half of  $V_{CC}$
- $B$  is the applied magnetic flux density
- $\text{Sensitivity}_{(25^\circ\text{C})}$  depends on the device option and  $V_{CC}$
- $S_{TC}$  is typically 0.12%/°C for device options DRV5055A1 - DRV5055A4 and is 0%/°C for DRV5055Z1 - DRV5055Z4 options
- $T_A$  is the ambient temperature
- $V_{OUT}$  is within the  $V_L$  range

As an example, consider the DRV5055A3 with  $V_{CC} = 3.3\text{ V}$ , a temperature of  $50^\circ\text{C}$ , and 67 mT applied. Excluding tolerances,  $V_{OUT} = 1650\text{ mV} + 67\text{ mT} \times (15\text{ mV/mT} \times (1 + 0.0012/^\circ\text{C} \times (50^\circ\text{C} - 25^\circ\text{C}))) = 2685\text{ mV}$ .

### 6.3.3 Sensitivity Linearity

The device produces a linear response when the output voltage is within the specified  $V_L$  range. Outside this range, sensitivity is reduced and nonlinear. 図 6-3 graphs the magnetic response.

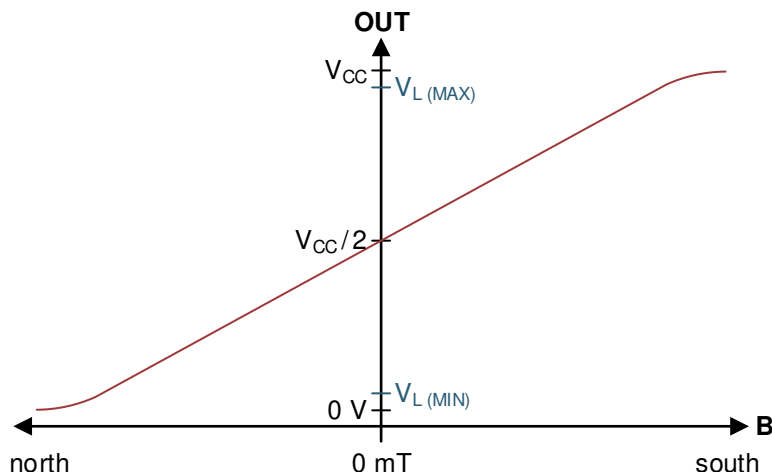


図 6-3. Magnetic Response

式 2 calculates parameter  $B_L$ , the minimum linear sensing range at 25°C taking into account the maximum quiescent voltage and sensitivity tolerances.

$$B_{L(MIN)} = \frac{V_{L(MAX)} - V_{Q(MAX)}}{S_{(MAX)}} \quad (2)$$

The parameter  $S_{LE}$  defines linearity error as the difference in sensitivity between any two positive  $B$  values, and any two negative  $B$  values, while the output is within the  $V_L$  range.

The parameter  $S_{SE}$  defines symmetry error as the difference in sensitivity between any positive  $B$  value and the negative  $B$  value of the same magnitude, while the output voltage is within the  $V_L$  range.

### 6.3.4 Ratiometric Architecture

The DRV5055 has a ratiometric analog architecture that scales the quiescent voltage and sensitivity linearly with the power-supply voltage. For example, the quiescent voltage and sensitivity are 5% higher when  $V_{CC} = 5.25$  V compared to  $V_{CC} = 5$  V. This behavior enables external ADCs to digitize a consistent value regardless of the power-supply voltage tolerance, when the ADC uses  $V_{CC}$  as its reference.

式 3 calculates the sensitivity ratiometry error:

$$S_{RE} = 1 - \frac{S_{(VCC)} / S_{(5V)}}{V_{CC} / 5V} \text{ for } V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}, \quad S_{RE} = 1 - \frac{S_{(VCC)} / S_{(3.3V)}}{V_{CC} / 3.3V} \text{ for } V_{CC} = 3 \text{ V to } 3.63 \text{ V} \quad (3)$$

where

- $S_{(VCC)}$  is the sensitivity at the current  $V_{CC}$  voltage
- $S_{(5V)}$  or  $S_{(3.3V)}$  is the sensitivity when  $V_{CC} = 5$  V or 3.3 V
- $V_{CC}$  is the current  $V_{CC}$  voltage

式 4 calculates quiescent voltage ratiometry error:

$$V_{QRE} = 1 - \frac{V_{Q(VCC)} / V_{Q(5V)}}{V_{CC} / 5V} \text{ for } V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}, \quad V_{QRE} = 1 - \frac{V_{Q(VCC)} / V_{Q(3.3V)}}{V_{CC} / 3.3V} \text{ for } V_{CC} = 3 \text{ V to } 3.63 \text{ V} \quad (4)$$

where

- $V_{Q(VCC)}$  is the quiescent voltage at the current  $V_{CC}$  voltage
- $V_{Q(5V)}$  or  $V_{Q(3.3V)}$  is the quiescent voltage when  $V_{CC} = 5$  V or 3.3 V

- $V_{CC}$  is the current  $V_{CC}$  voltage

### 6.3.5 Operating $V_{CC}$ Ranges

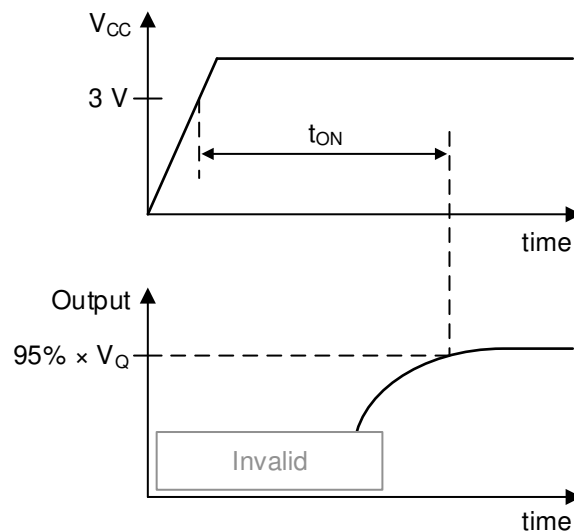
The DRV5055 has two recommended operating  $V_{CC}$  ranges: 3 V to 3.63 V and 4.5 V to 5.5 V. When  $V_{CC}$  is in the middle region between 3.63 V to 4.5 V, the device continues to function, but sensitivity is less known because there is a crossover threshold near 4 V that adjusts device characteristics.

### 6.3.6 Sensitivity Temperature Compensation for Magnets

Magnets generally produce weaker fields as temperature increases. The DRV5055 can either compensate by increasing sensitivity with temperature or by keeping the sensitivity constant, as defined by the parameters  $S_{TC}$  and  $S_{TCZ}$ , respectively. For device options DRV5055A1 - DRV5055A4, the sensitivity at  $T_A = 125^\circ\text{C}$  is typically 12% higher than at  $T_A = 25^\circ\text{C}$ . For device options DRV5055Z1 - DRV5055Z4, the sensitivity at  $T_A = 125^\circ\text{C}$  is typically same as the value at  $T_A = 25^\circ\text{C}$ .

### 6.3.7 Power-On Time

After the  $V_{CC}$  voltage is applied, the DRV5055 requires a short initialization time before the output is set. The parameter  $t_{ON}$  describes the time from when  $V_{CC}$  crosses 3 V until OUT is within 5% of  $V_Q$ , with 0 mT applied and no load attached to OUT. [Figure 6-4](#) shows this timing diagram.



**Figure 6-4.  $t_{ON}$  Definition**

### 6.3.8 Hall Element Location

Figure 6-5 shows the location of the sensing element inside each package option.

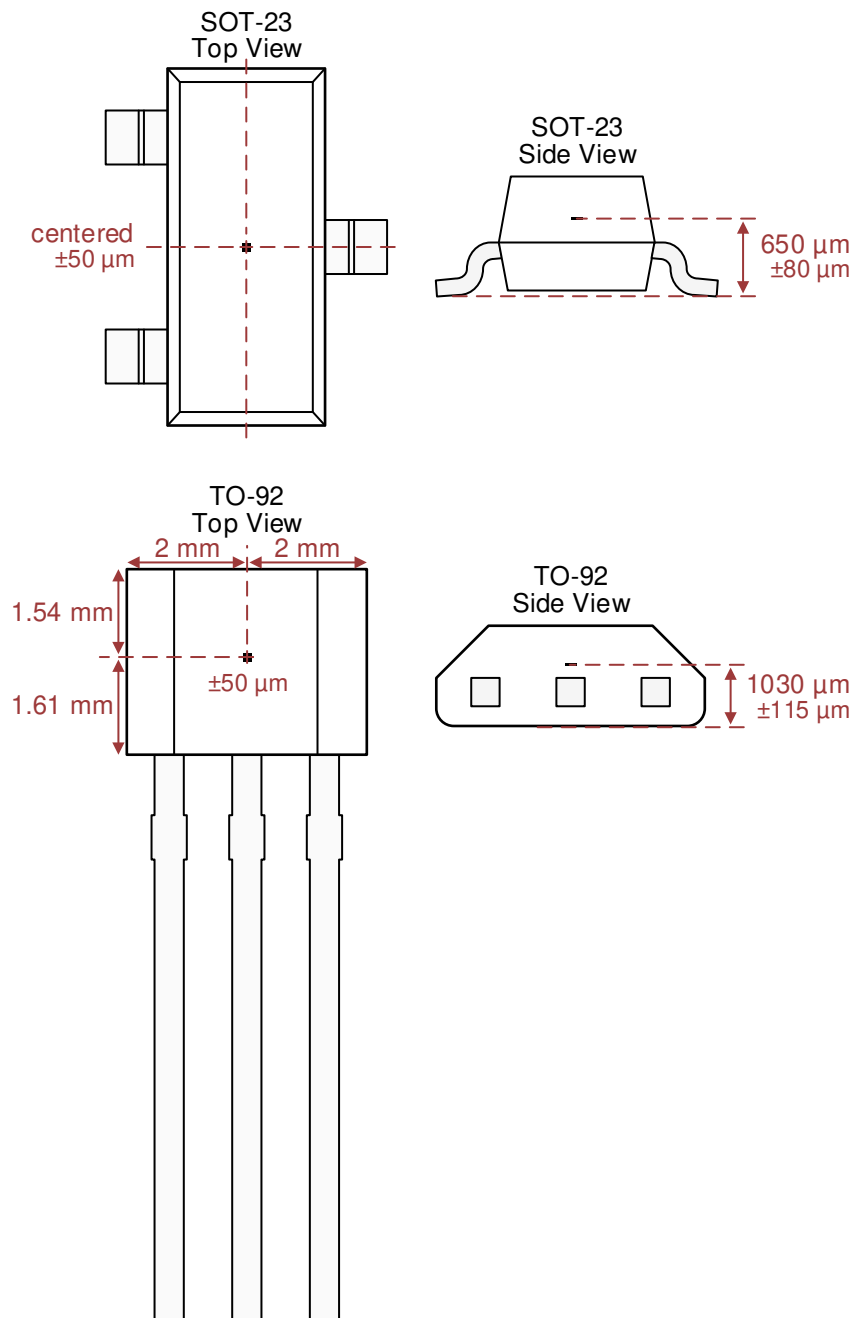


Figure 6-5. Hall Element Location

### 6.4 Device Functional Modes

The DRV5055 has one mode of operation that applies when the *Recommended Operating Conditions* are met.

## 7 Application and Implementation

### 注

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

### 7.1 Application Information

#### 7.1.1 Selecting the Sensitivity Option

Select the highest DRV5055 sensitivity option that can measure the required range of magnetic flux density, so that the output voltage swing is maximized.

Larger-sized magnets and farther sensing distances can generally enable better positional accuracy than very small magnets at close distances, because magnetic flux density increases exponentially with the proximity to a magnet. TI created an online tool to help with simple magnet calculations at <https://www.ti.com/product/drv5013>.

#### 7.1.2 Temperature Compensation for Magnets

The DRV5055 temperature compensation is designed to directly compensate the average drift of neodymium (NdFeB) magnets and partially compensate ferrite magnets. The residual induction ( $B_r$ ) of a magnet typically reduces by 0.12%/°C for NdFeB, and 0.20%/°C for ferrite. When the operating temperature of a system is reduced, temperature drift errors are also reduced.

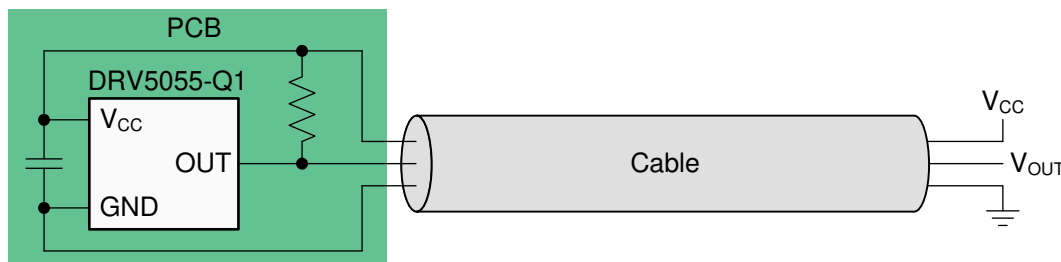
#### 7.1.3 Adding a Low-Pass Filter

As shown in [Functional Block Diagram](#), an RC low-pass filter can be added to the device output for the purpose of minimizing voltage noise when the full 20-kHz bandwidth is not needed. This filter can improve the signal-to-noise ratio (SNR) and overall accuracy. Do not connect a capacitor directly to the device output without a resistor in between because doing so can make the output unstable.

#### 7.1.4 Designing for Wire Break Detection

Some systems must detect if interconnect wires become open or shorted. The DRV5055 can support this function.

First, select a sensitivity option that causes the output voltage to stay within the  $V_L$  range during normal operation. Second, add a pullup resistor between OUT and  $V_{CC}$ . TI recommends a value between 20 k $\Omega$  to 100 k $\Omega$ , and the current through OUT must not exceed the  $I_O$  specification, including current going into an external ADC. Then, if the output voltage is ever measured to be within 150 mV of  $V_{CC}$  or GND, a fault condition exists. [図 7-1](#) shows the circuit, and [表 7-1](#) describes fault scenarios.

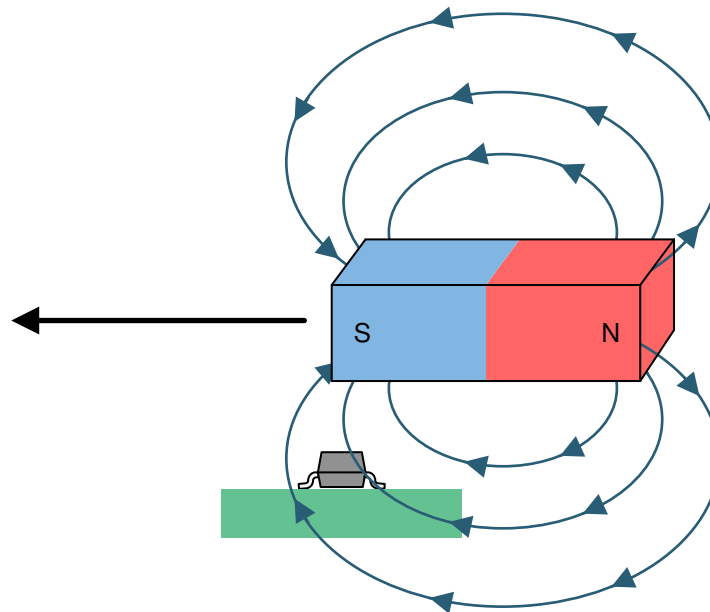


**図 7-1. Wire Fault Detection Circuit**

**表 7-1. Fault Scenarios and the Resulting  $V_{OUT}$** 

| FAULT SCENARIO         | $V_{OUT}$         |
|------------------------|-------------------|
| $V_{CC}$ disconnects   | Close to GND      |
| GND disconnects        | Close to $V_{CC}$ |
| $V_{CC}$ shorts to OUT | Close to $V_{CC}$ |
| GND shorts to OUT      | Close to GND      |

## 7.2 Typical Application

**図 7-2. Common Magnet Orientation**

### 7.2.1 Design Requirements

Use the parameters listed in 表 7-2 for this design example.

**表 7-2. Design Parameters**

| DESIGN PARAMETER                | EXAMPLE VALUE       |
|---------------------------------|---------------------|
| $V_{CC}$                        | 5 V                 |
| Magnet                          | 15 × 5 × 5 mm NdFeB |
| Travel distance                 | 12 mm               |
| Maximum B at the sensor at 25°C | ±75 mT              |
| Device option                   | DRV5055A3           |

### 7.2.2 Detailed Design Procedure

Linear Hall effect sensors provide flexibility in mechanical design, because many possible magnet orientations and movements produce a usable response from the sensor. 図 7-2 shows one of the most common orientations, which uses the full north to south range of the sensor and causes a close-to-linear change in magnetic flux density as the magnet moves across.

When designing a linear magnetic sensing system, always consider these three variables: the magnet, sensing distance, and the range of the sensor. Select the DRV5055 with the highest sensitivity that has a  $B_L$  (linear magnetic sensing range) that is larger than the maximum magnetic flux density in the application. To determine



the magnetic flux density the sensor receives, TI recommends using magnetic field simulation software, referring to magnet specifications, and testing.

### 7.2.3 Application Curve

Figure 7-3 shows the simulated magnetic flux from a NdFeB magnet.

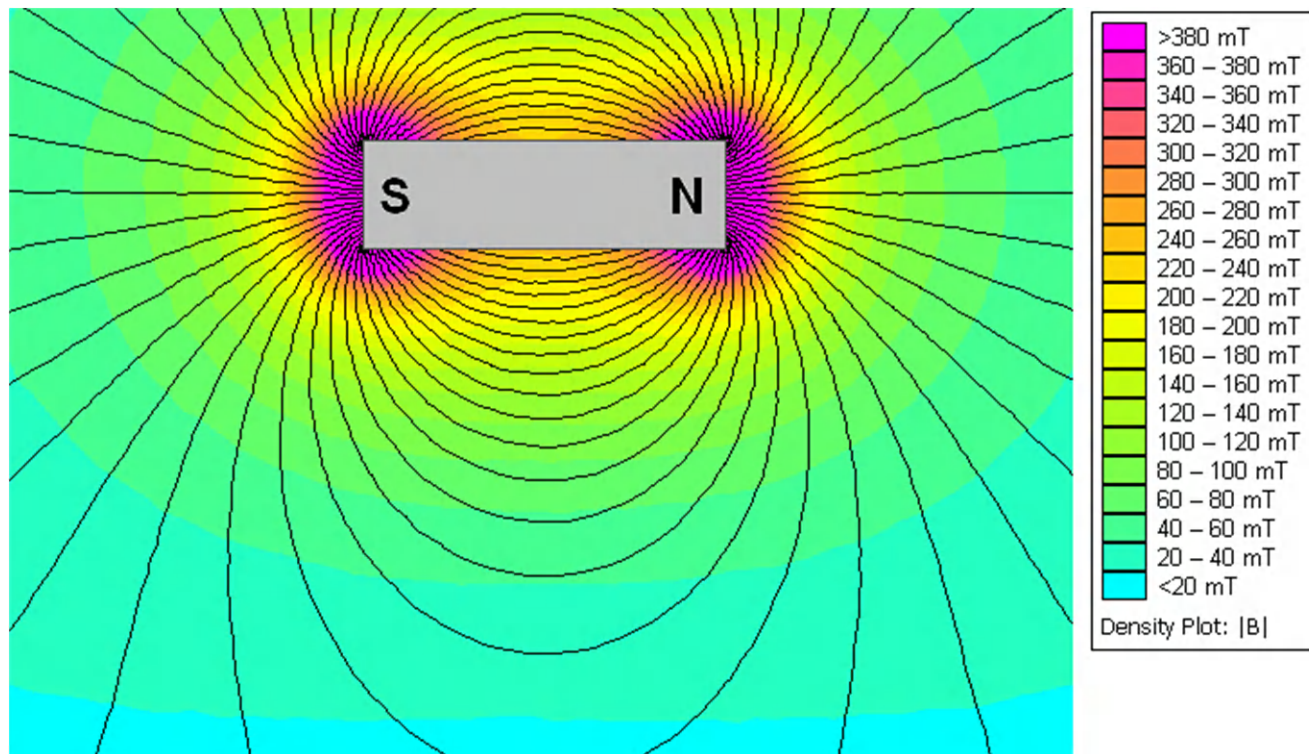


Figure 7-3. Simulated Magnetic Flux

### 7.3 Best Design Practices

Because the Hall element is sensitive to magnetic fields that are perpendicular to the top of the package, a correct magnet approach must be used for the sensor to detect the field. 図 7-4 shows correct and incorrect approaches.

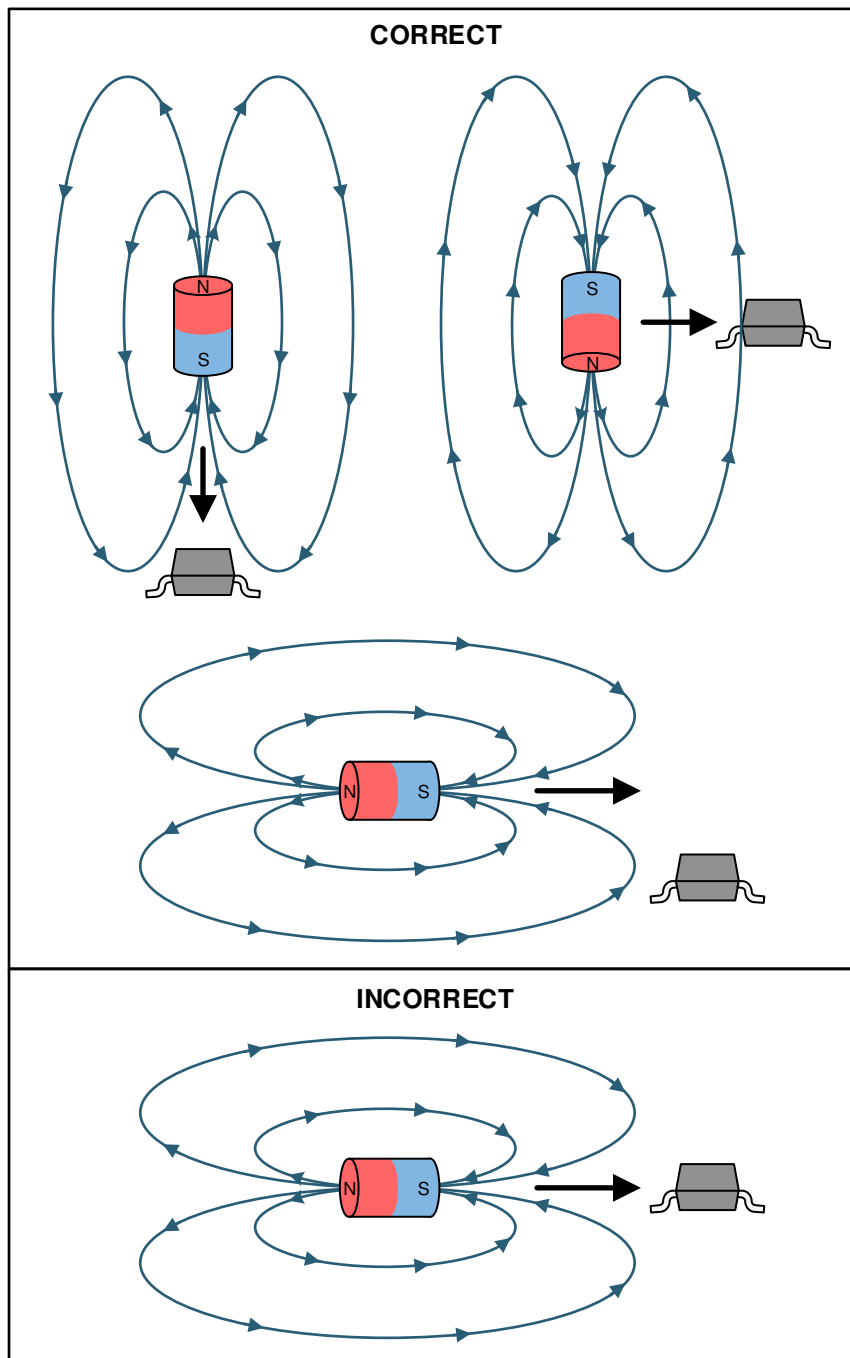


図 7-4. Correct and Incorrect Magnet Approaches

## 7.4 Power Supply Recommendations

A decoupling capacitor close to the device must be used to provide local energy with minimal inductance. TI recommends using a ceramic capacitor with a value of at least 0.01  $\mu\text{F}$ .

## 7.5 Layout

### 7.5.1 Layout Guidelines

Magnetic fields pass through most nonferromagnetic materials with no significant disturbance. Embedding Hall effect sensors within plastic or aluminum enclosures and sensing magnets on the outside is common practice. Magnetic fields also easily pass through most printed-circuit boards, which makes placing the magnet on the opposite side possible.

### 7.5.2 Layout Examples

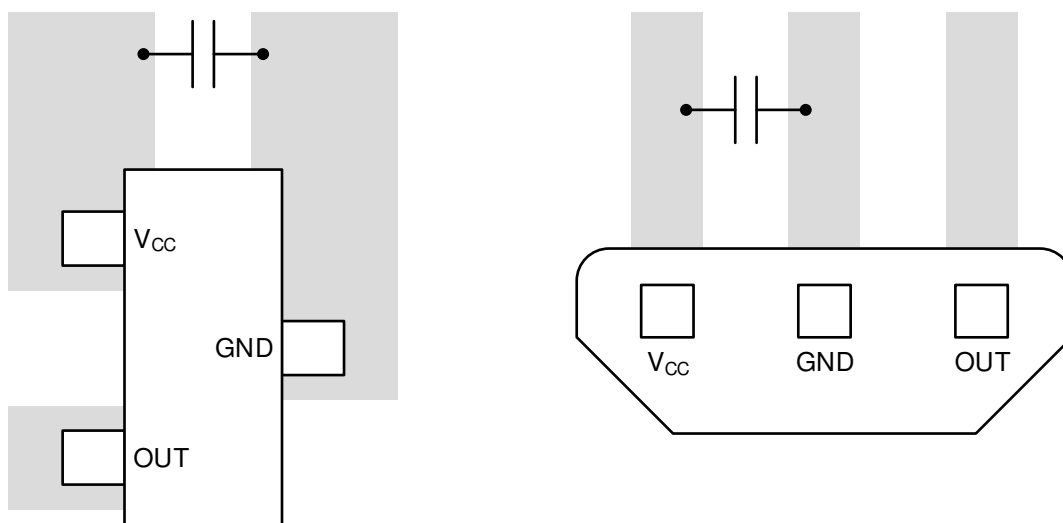


図 7-5. Layout Examples

## 8 Device and Documentation Support

### 8.1 Documentation Support

#### 8.1.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [Overview Using Linear Hall Effect Sensors to Measure Angle application brief](#)
- Texas Instruments, [Incremental Rotary Encoder Design Considerations application brief](#)

### 8.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[www.tij.co.jp](http://www.tij.co.jp) のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

### 8.3 サポート・リソース

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### 8.6 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

## 9 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

| Changes from Revision B (April 2021) to Revision C (December 2023)                                    | Page |
|-------------------------------------------------------------------------------------------------------|------|
| • Changed the operating supply current and power-on time parameters.....                              | 5    |
| • Added the maximum propagation delay time value.....                                                 | 5    |
| • Added test conditions to the quiescent voltage temperature drift parameter.....                     | 6    |
| • Added the maximum quiescent voltage lifetime drift value to the Magnetic Characteristics table..... | 6    |
| • Added the sensitivity linearity lifetime drift parameter to the Magnetic Characteristics table..... | 6    |
| Changes from Revision A (June 2020) to Revision B (April 2021)                                        | Page |
| • ドキュメント全体にわたって表、図、相互参照の採番方法を更新.....                                                                  | 1    |
| • Changed the absolute maximum operating junction temperature from: 150°C to: 170°C.....              | 4    |
| • Removed the Product Preview tablenote from the Magnetic Characteristics table.....                  | 6    |
| Changes from Revision * (January 2018) to Revision A (June 2020)                                      | Page |
| • データシートにゼロ TC 感度オプションを追加.....                                                                        | 1    |

|                                                                                                        |    |
|--------------------------------------------------------------------------------------------------------|----|
| • Added Zero TC information to the Electrical Characteristics.....                                     | 5  |
| • Added Zero TC information to the Magnetic Characteristics table.....                                 | 6  |
| • Added graphs for DV5055Z1/Z2/Z3/Z4 options in the <i>Typical Characteristics</i> section.....        | 7  |
| • Updated $S_{TC}$ definition in 式 1 .....                                                             | 11 |
| • Updated the <i>Sensitivity Temperature Compensation for Magnets</i> section for Zero TC options..... | 13 |

## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable part number          | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|--------------------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">DRV5055A1QDBZR</a> | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A1                |
| DRV5055A1QDBZR.A               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A1                |
| DRV5055A1QDBZR.B               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A1                |
| <a href="#">DRV5055A1QLPG</a>  | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A1                |
| DRV5055A1QLPG.A                | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A1                |
| DRV5055A1QLPG.B                | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A1                |
| <a href="#">DRV5055A1QLPGM</a> | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A1                |
| DRV5055A1QLPGM.A               | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A1                |
| DRV5055A1QLPGM.B               | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A1                |
| <a href="#">DRV5055A2QDBZR</a> | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A2                |
| DRV5055A2QDBZR.A               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A2                |
| DRV5055A2QDBZR.B               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A2                |
| <a href="#">DRV5055A2QLPG</a>  | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A2                |
| DRV5055A2QLPG.A                | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A2                |
| DRV5055A2QLPG.B                | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A2                |
| <a href="#">DRV5055A2QLPGM</a> | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A2                |
| DRV5055A2QLPGM.A               | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A2                |
| DRV5055A2QLPGM.B               | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A2                |
| <a href="#">DRV5055A3QDBZR</a> | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A3                |
| DRV5055A3QDBZR.A               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A3                |
| DRV5055A3QDBZR.B               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A3                |
| <a href="#">DRV5055A3QDBZT</a> | Obsolete      | Production           | SOT-23 (DBZ)   3 | -                     | -           | Call TI                              | Call TI                           | -40 to 125   | 55A3                |
| <a href="#">DRV5055A3QLPG</a>  | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A3                |
| DRV5055A3QLPG.A                | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A3                |
| DRV5055A3QLPG.B                | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A3                |
| <a href="#">DRV5055A3QLPGM</a> | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A3                |
| DRV5055A3QLPGM.A               | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A3                |
| DRV5055A3QLPGM.B               | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A3                |
| <a href="#">DRV5055A4QDBZR</a> | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A4                |

| Orderable part number          | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|--------------------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| DRV5055A4QDBZR.A               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A4                |
| DRV5055A4QDBZR.B               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55A4                |
| <a href="#">DRV5055A4QDBZT</a> | Obsolete      | Production           | SOT-23 (DBZ)   3 | -                     | -           | Call TI                              | Call TI                           | -40 to 125   | 55A4                |
| <a href="#">DRV5055A4QLPG</a>  | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A4                |
| DRV5055A4QLPG.A                | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A4                |
| DRV5055A4QLPG.B                | Active        | Production           | TO-92 (LPG)   3  | 1000   BULK           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A4                |
| <a href="#">DRV5055A4QLPGM</a> | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A4                |
| DRV5055A4QLPGM.A               | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A4                |
| DRV5055A4QLPGM.B               | Active        | Production           | TO-92 (LPG)   3  | 3000   AMMO           | Yes         | SN                                   | N/A for Pkg Type                  | -40 to 125   | 55A4                |
| <a href="#">DRV5055Z1QDBZR</a> | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z1                |
| DRV5055Z1QDBZR.A               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z1                |
| DRV5055Z1QDBZR.B               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z1                |
| <a href="#">DRV5055Z1QDBZT</a> | Obsolete      | Production           | SOT-23 (DBZ)   3 | -                     | -           | Call TI                              | Call TI                           | -40 to 125   | 55Z1                |
| <a href="#">DRV5055Z2QDBZR</a> | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z2                |
| DRV5055Z2QDBZR.A               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z2                |
| DRV5055Z2QDBZR.B               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z2                |
| <a href="#">DRV5055Z2QDBZT</a> | Obsolete      | Production           | SOT-23 (DBZ)   3 | -                     | -           | Call TI                              | Call TI                           | -40 to 125   | 55Z2                |
| <a href="#">DRV5055Z3QDBZR</a> | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z3                |
| DRV5055Z3QDBZR.A               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z3                |
| DRV5055Z3QDBZR.B               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z3                |
| <a href="#">DRV5055Z3QDBZT</a> | Obsolete      | Production           | SOT-23 (DBZ)   3 | -                     | -           | Call TI                              | Call TI                           | -40 to 125   | 55Z3                |
| <a href="#">DRV5055Z4QDBZR</a> | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z4                |
| DRV5055Z4QDBZR.A               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z4                |
| DRV5055Z4QDBZR.B               | Active        | Production           | SOT-23 (DBZ)   3 | 3000   LARGE T&R      | Yes         | SN                                   | Level-2-260C-1 YEAR               | -40 to 125   | 55Z4                |
| <a href="#">DRV5055Z4QDBZT</a> | Obsolete      | Production           | SOT-23 (DBZ)   3 | -                     | -           | Call TI                              | Call TI                           | -40 to 125   | 55Z4                |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.



<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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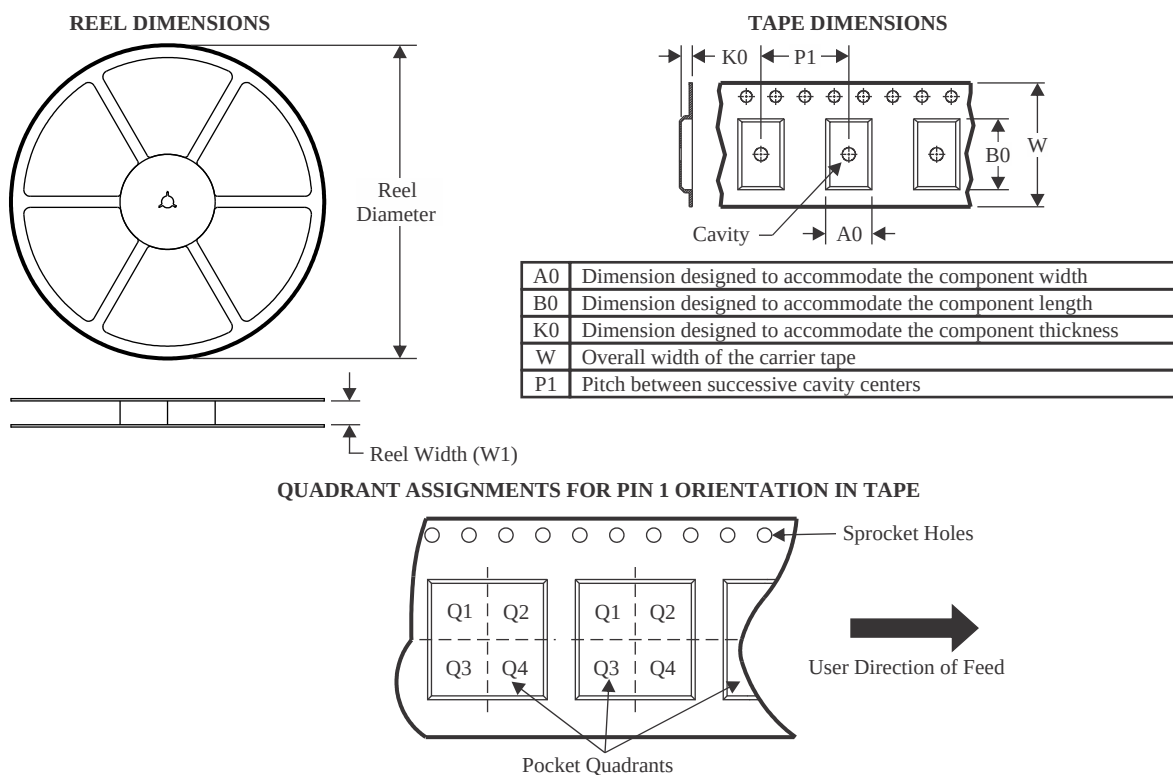
**OTHER QUALIFIED VERSIONS OF DRV5055 :**

- Automotive : [DRV5055-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



**TAPE AND REEL INFORMATION**


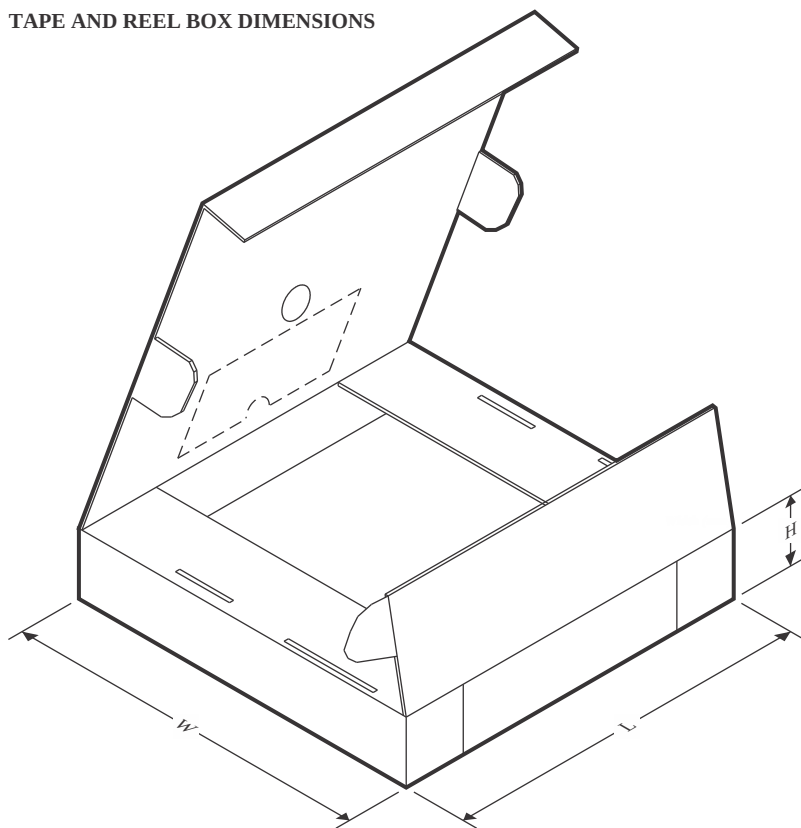
\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| DRV5055A1QDBZR | SOT-23       | DBZ             | 3    | 3000 | 178.0              | 9.0                | 3.15    | 2.77    | 1.22    | 4.0     | 8.0    | Q3            |
| DRV5055A2QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.2     | 2.85    | 1.3     | 4.0     | 8.0    | Q3            |
| DRV5055A2QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.15    | 2.77    | 1.22    | 4.0     | 8.0    | Q3            |
| DRV5055A2QDBZR | SOT-23       | DBZ             | 3    | 3000 | 178.0              | 9.0                | 3.15    | 2.77    | 1.22    | 4.0     | 8.0    | Q3            |
| DRV5055A3QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.15    | 2.77    | 1.22    | 4.0     | 8.0    | Q3            |
| DRV5055A3QDBZR | SOT-23       | DBZ             | 3    | 3000 | 178.0              | 9.0                | 3.15    | 2.77    | 1.22    | 4.0     | 8.0    | Q3            |
| DRV5055A3QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.2     | 2.85    | 1.3     | 4.0     | 8.0    | Q3            |
| DRV5055A4QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.2     | 2.85    | 1.3     | 4.0     | 8.0    | Q3            |
| DRV5055A4QDBZR | SOT-23       | DBZ             | 3    | 3000 | 178.0              | 9.0                | 3.15    | 2.77    | 1.22    | 4.0     | 8.0    | Q3            |
| DRV5055Z1QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.2     | 2.85    | 1.3     | 4.0     | 8.0    | Q3            |
| DRV5055Z1QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.2     | 2.85    | 1.3     | 4.0     | 8.0    | Q3            |
| DRV5055Z2QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.2     | 2.85    | 1.3     | 4.0     | 8.0    | Q3            |
| DRV5055Z2QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.15    | 2.77    | 1.22    | 4.0     | 8.0    | Q3            |
| DRV5055Z3QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.2     | 2.85    | 1.3     | 4.0     | 8.0    | Q3            |
| DRV5055Z3QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.2     | 2.85    | 1.3     | 4.0     | 8.0    | Q3            |
| DRV5055Z4QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.2     | 2.85    | 1.3     | 4.0     | 8.0    | Q3            |

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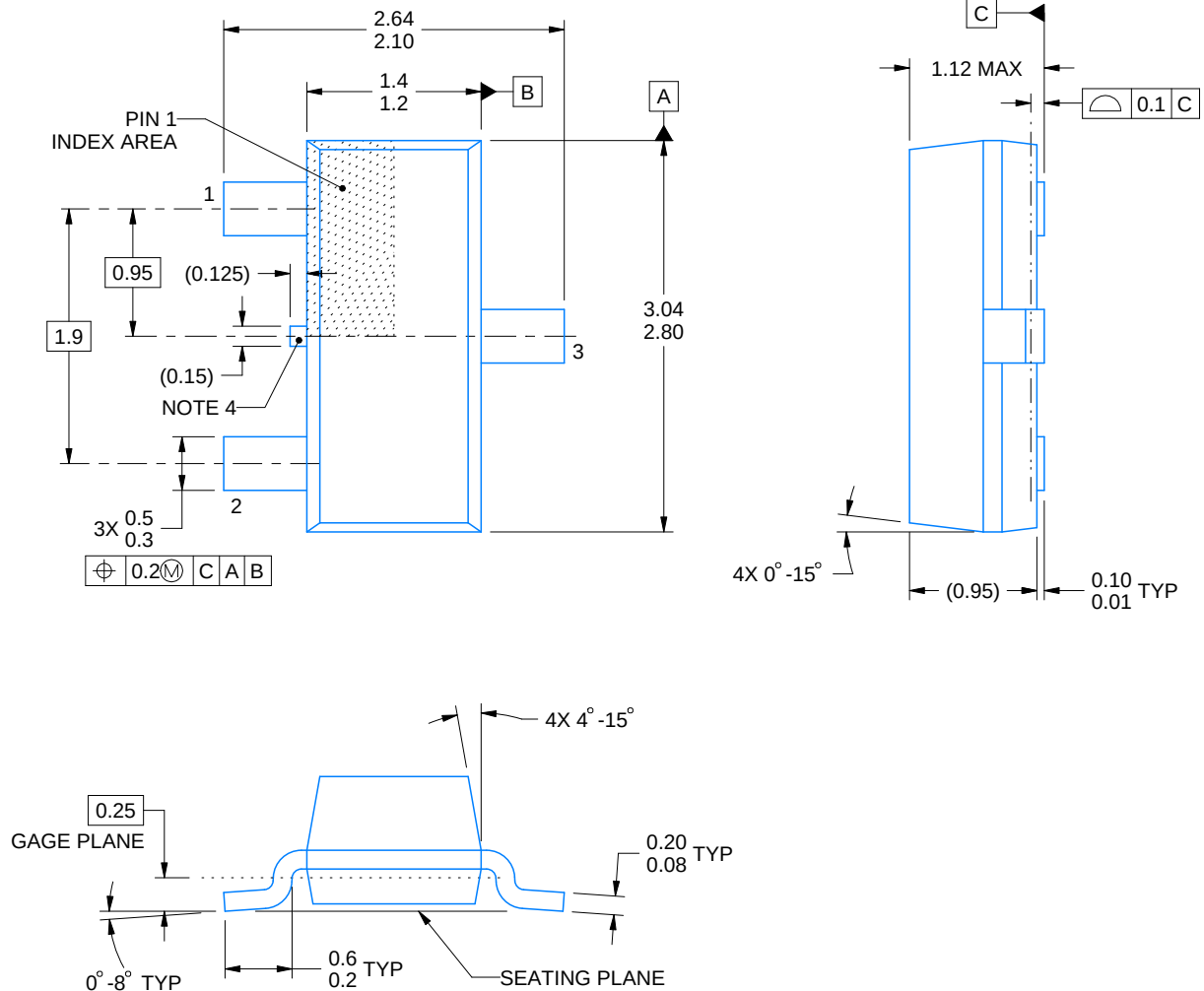
| Device         | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| DRV5055Z4QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0              | 8.4                | 3.2     | 2.85    | 1.3     | 4.0     | 8.0    | Q3            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| DRV5055A1QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0       | 180.0      | 18.0        |
| DRV5055A2QDBZR | SOT-23       | DBZ             | 3    | 3000 | 210.0       | 185.0      | 35.0        |
| DRV5055A2QDBZR | SOT-23       | DBZ             | 3    | 3000 | 213.0       | 191.0      | 35.0        |
| DRV5055A2QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0       | 180.0      | 18.0        |
| DRV5055A3QDBZR | SOT-23       | DBZ             | 3    | 3000 | 213.0       | 191.0      | 35.0        |
| DRV5055A3QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0       | 180.0      | 18.0        |
| DRV5055A3QDBZR | SOT-23       | DBZ             | 3    | 3000 | 210.0       | 185.0      | 35.0        |
| DRV5055A4QDBZR | SOT-23       | DBZ             | 3    | 3000 | 210.0       | 185.0      | 35.0        |
| DRV5055A4QDBZR | SOT-23       | DBZ             | 3    | 3000 | 180.0       | 180.0      | 18.0        |
| DRV5055Z1QDBZR | SOT-23       | DBZ             | 3    | 3000 | 210.0       | 185.0      | 35.0        |
| DRV5055Z1QDBZR | SOT-23       | DBZ             | 3    | 3000 | 210.0       | 185.0      | 35.0        |
| DRV5055Z2QDBZR | SOT-23       | DBZ             | 3    | 3000 | 210.0       | 185.0      | 35.0        |
| DRV5055Z2QDBZR | SOT-23       | DBZ             | 3    | 3000 | 213.0       | 191.0      | 35.0        |
| DRV5055Z3QDBZR | SOT-23       | DBZ             | 3    | 3000 | 210.0       | 185.0      | 35.0        |
| DRV5055Z3QDBZR | SOT-23       | DBZ             | 3    | 3000 | 210.0       | 185.0      | 35.0        |
| DRV5055Z4QDBZR | SOT-23       | DBZ             | 3    | 3000 | 210.0       | 185.0      | 35.0        |
| DRV5055Z4QDBZR | SOT-23       | DBZ             | 3    | 3000 | 210.0       | 185.0      | 35.0        |



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## NOTES:

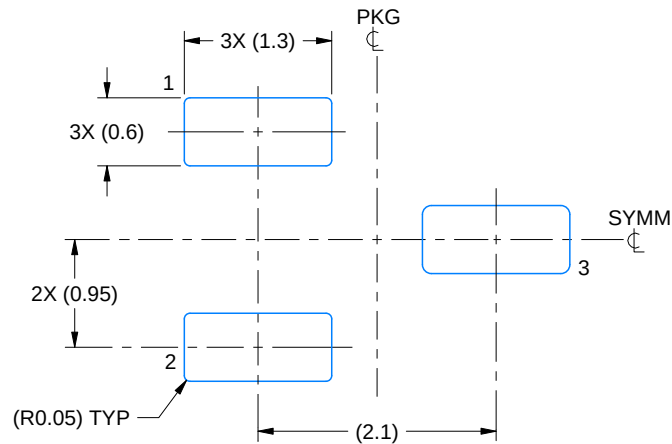
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-236, except minimum foot length.
4. Support pin may differ or may not be present.
5. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

# EXAMPLE BOARD LAYOUT

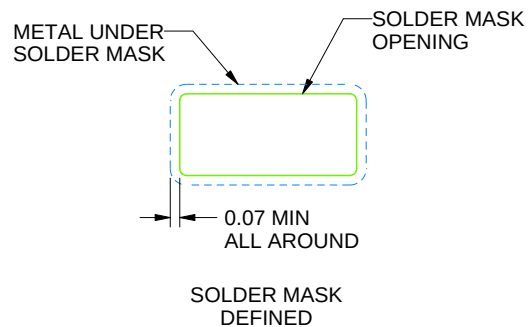
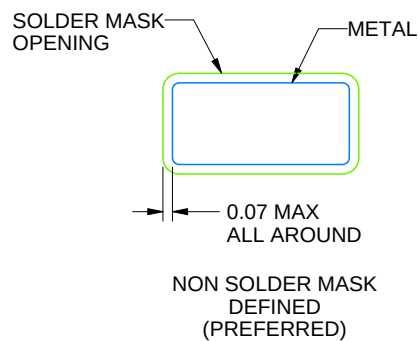
DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
SCALE:15X



SOLDER MASK DETAILS

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NOTES: (continued)

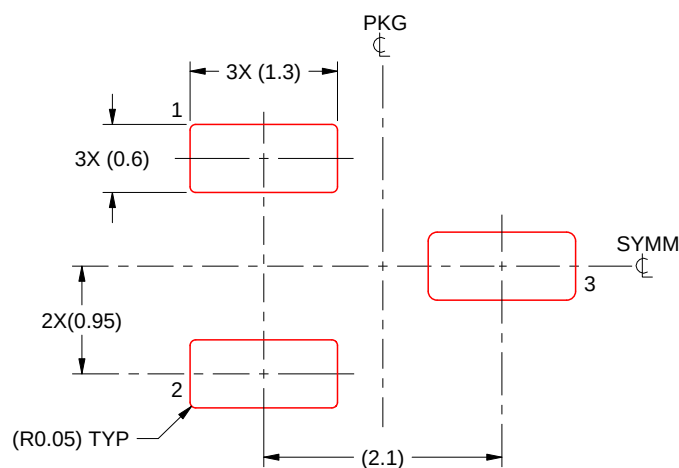
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



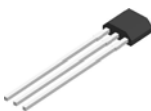
SOLDER PASTE EXAMPLE  
BASED ON 0.125 THICK STENCIL  
SCALE:15X

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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

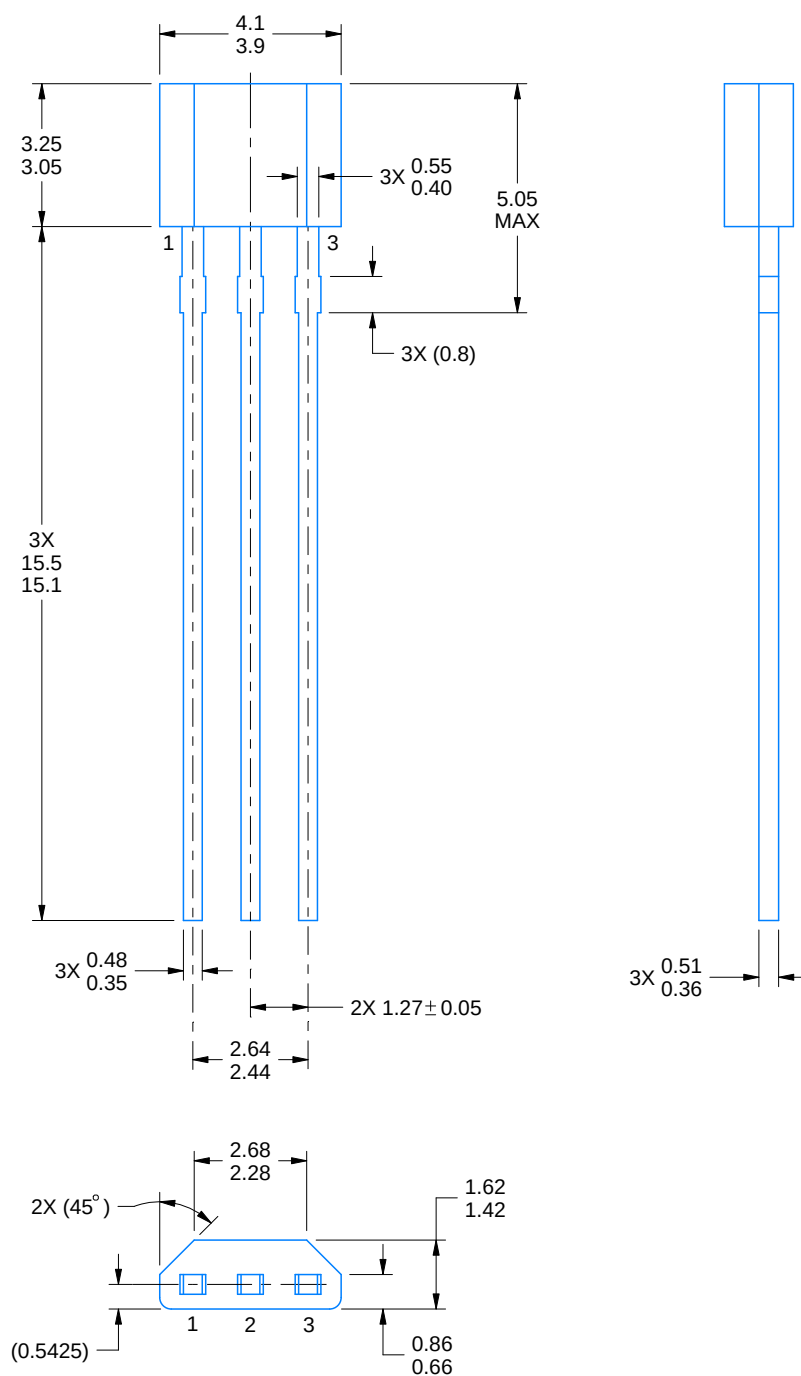
LPG0003A



## PACKAGE OUTLINE

TO-92 - 5.05 mm max height

TRANSISTOR OUTLINE



4221343/C 01/2018

### NOTES:

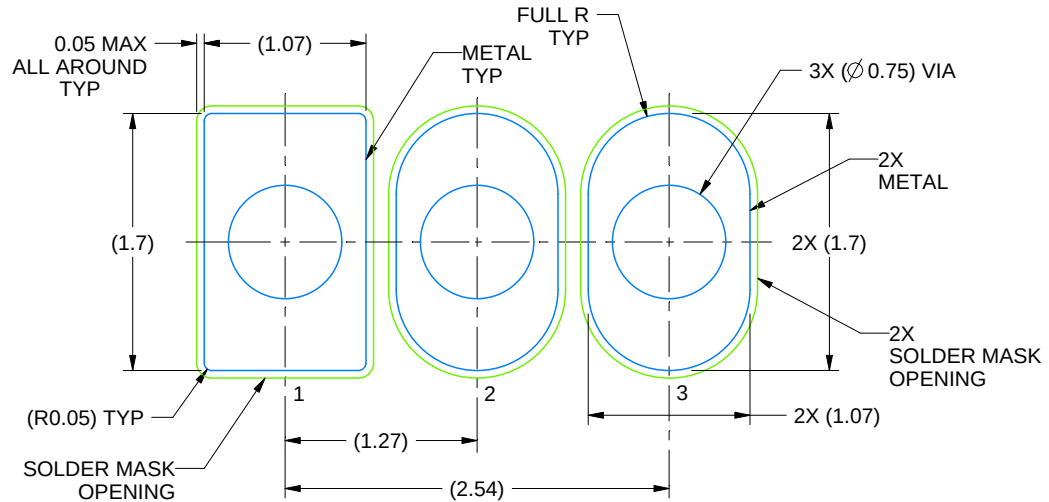
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

# EXAMPLE BOARD LAYOUT

LPG0003A

TO-92 - 5.05 mm max height

TRANSISTOR OUTLINE



LAND PATTERN EXAMPLE  
NON-SOLDER MASK DEFINED  
SCALE:20X

4221343/C 01/2018

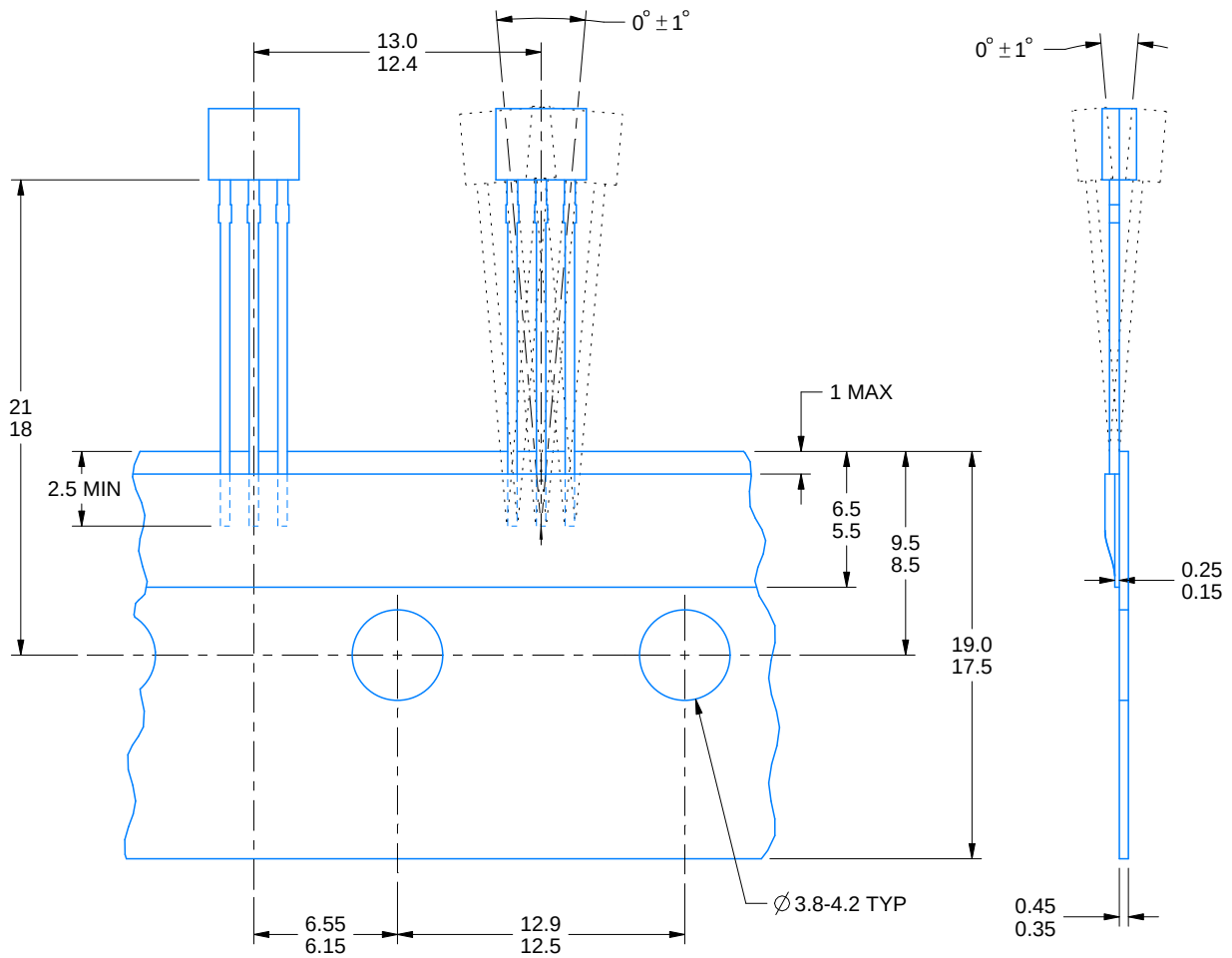


# TAPE SPECIFICATIONS

LPG0003A

TO-92 - 5.05 mm max height

TRANSISTOR OUTLINE



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最終更新日：2025 年 10 月